# NSN 5961-00-752-0152

Transistor - Page 1 of 1



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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.250 inches and 0.450 inches

# **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

#### **Internal Configuration:**

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 65.0 breakdown voltage, collector-to-emitter, base open and 60.0

breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

5.00 amperes source cutoff current and 20.00 amperes source cutoff current

#### Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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